

Photointerrupters(Transmissive)

KODENSHI

SG - 222V

The SG - 222V photointerrupter high - performance standard type, combines high - output GaAs IRED with high sensitive phototransistor. Compact size.

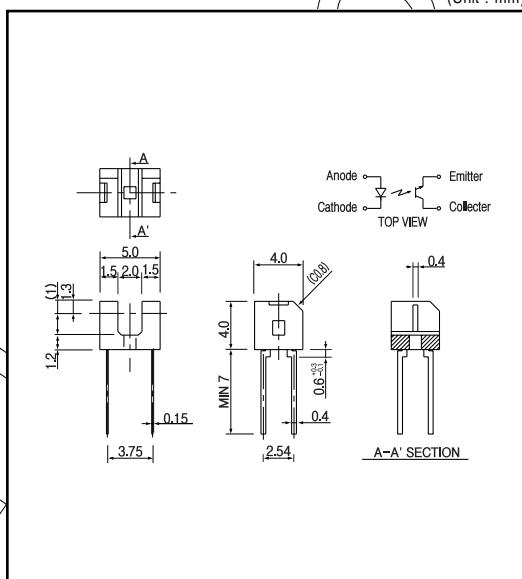
FEATURES

- PWB direct mount type
- GAP : 2.0mm
- Low - boy type(installation height :4.0mm)

APPLICATIONS

- Floppy disk drives
- Mini printers
- Handy copiers
- Car stereo
- Scanners

DIMENSIONS



MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Input	P _D	75	mW
	I _F	50	mA
	V _R	5	V
	I _{FP}	0.5	A
Output	P _C	75	mW
	I _C	20	mA
	V _{CEO}	30	V
	V _{ECD}	5	V
Operating temp. ¹	T _{opr.}	- 20 ~ + 85	
Storage temp. ²	T _{stg.}	- 30 ~ + 100	
Soldering temp. ³	T _{sol.}	260	

*1. pulse width : t w 100 μ sec.period : T = 10msec.

*2. No icebound or dew

*3. For MAX.5 seconds at the position of 1mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

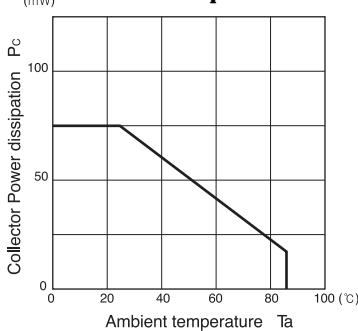
(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V _F	I _F =20mA		1.2	1.4	V
	I _R	V _R =5V			10	μ A
	p	I _F =20mA		940		nm
Output	I _{CEO}	V _{CE} =10V			100	nA
	I _C	I _F =20mA, V _E =5V(Non-shading)	0.5		3	mA
Transistor	I _{CEO}	I _F =10mA, V _E =5V(shading)		0.5	10	μ A
	V _{CE(sat)}	I _F =10mA, I _C =0.03mA			0.4	V
	tr	V _{CC} =5V, I _F =0.1mA, R=1k		50		μ sec.
	tf	V _{CC} =5V, I _F =0.1mA, R=1k		50		μ sec.

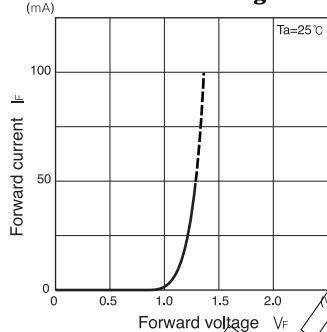
Photo interrupters(Transmissive)

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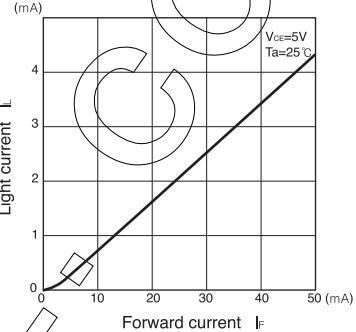
**Collector power dissipation Vs.
Ambient temperature**



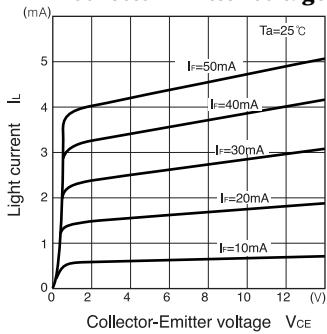
**Forward current Vs.
Forward voltage**



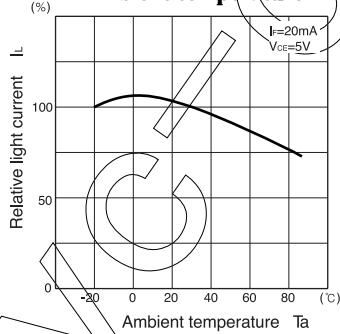
**Light current Vs.
Forward current**



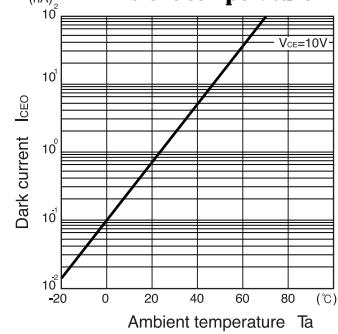
**Light current Vs.
Collector-Emitter voltage**



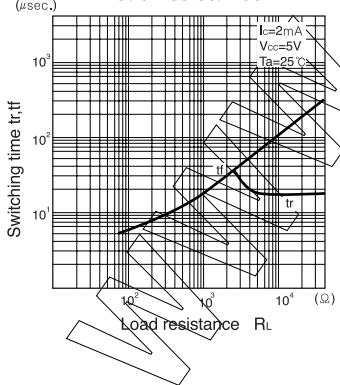
**Relative light current Vs.
Ambient temperature**



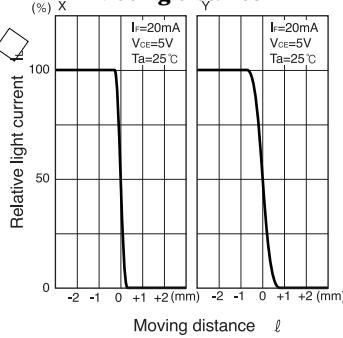
**Dark current Vs.
Ambient temperature**



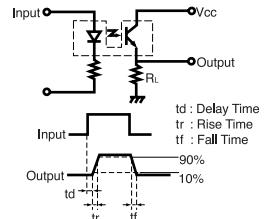
**Switching time Vs.
Load resistance**



**Relative light current Vs.
Moving distance**



Switching time measurement circuit



Method of measuring position detection characteristic

